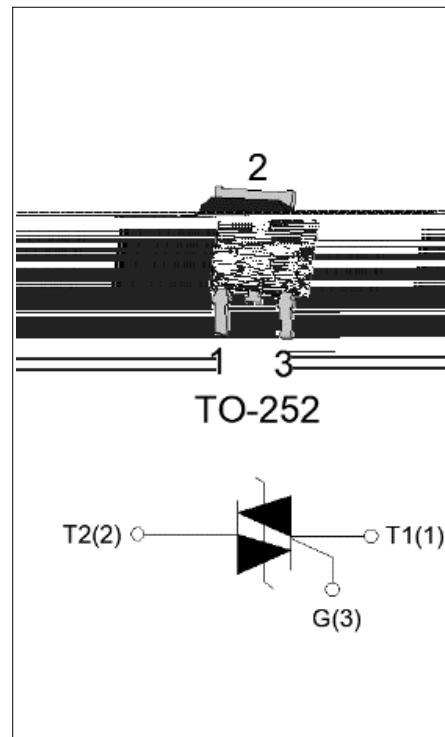




The ACJT610-8K triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. The ACJT610-8K embeds a TVS structure to absorb the inductive turn-off energy such as those described in the IEC 61000-4-5 standards. Package TO-252 is RoHS compliant.



Symbol	Value	Unit
$I_{T(\text{RMS})}$	6	A
$V_{\text{DRM}} / V_{\text{RRM}}$	800	V
$I_{\text{GT}}$ / /	10/10/10	mA

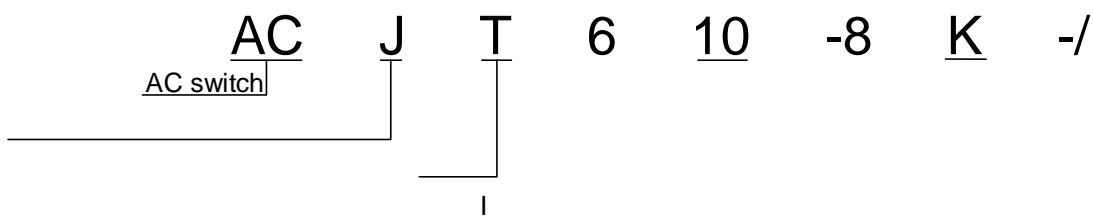
Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{\text{stg}}$	-40-150	
Operating junction temperature range	$T_j$	-40-125	
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{\text{DRM}}$	800	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{\text{RRM}}$	800	V
RMS on-state current ( $T_c = 91^\circ\text{C}$ )	$I_{T(\text{RMS})}$	6	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{\text{TSM}}$	60	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		66	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	18	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{\text{GT}}$ , $f=100\text{Hz}$ , $T_j=125^\circ\text{C}$ )	$dI/dt$	100	$\text{A}/\mu\text{s}$
Peak gate current ( $t_p=20\mu\text{s}$ , $T_j=125^\circ\text{C}$ )	$I_{\text{GM}}$	4	A
Average gate power dissipation ( $T_j=125^\circ\text{C}$ )	$P_{\text{G(AV)}}$	0.5	W
Peak gate power	$P_{\text{GM}}$	10	W

Peak pulse voltage (T <sub>j</sub> =25 °C; non-repetitive, off-state; FIG.8)	V <sub>pp</sub>	3.5	kV
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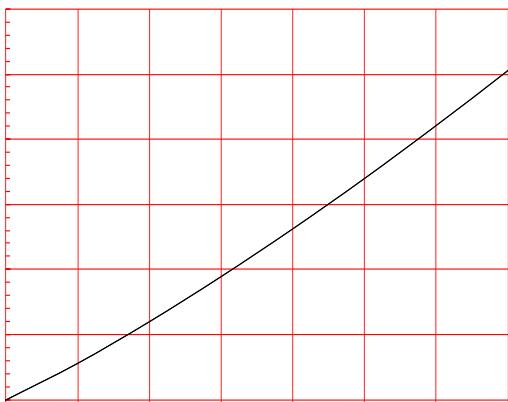
(T<sub>j</sub>=25 °C unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I <sub>GT</sub>	V <sub>D</sub> =12V R <sub>L</sub> =33	- -	MAX.	10	mA
V <sub>GT</sub>		- -	MAX.	1	V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =125 °C R <sub>L</sub> =3.3K	- -	MIN.	0.2	V
I <sub>L</sub>	I <sub>G</sub> =1.2I <sub>GT</sub>	-	MAX.	20	mA
				35	
I <sub>H</sub>	I <sub>T</sub> =100mA		MAX.	20	mA
dV/dt	V <sub>D</sub> =540V Gate Open T <sub>j</sub> =125 °C		MIN.	500	V/μs

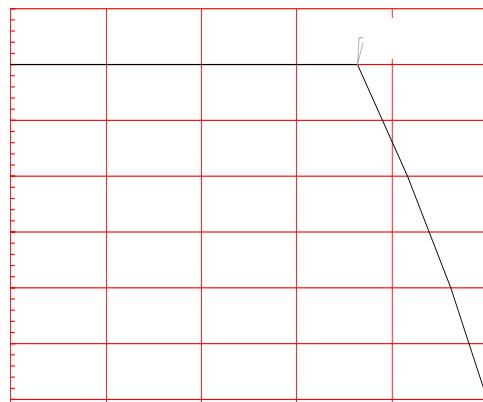
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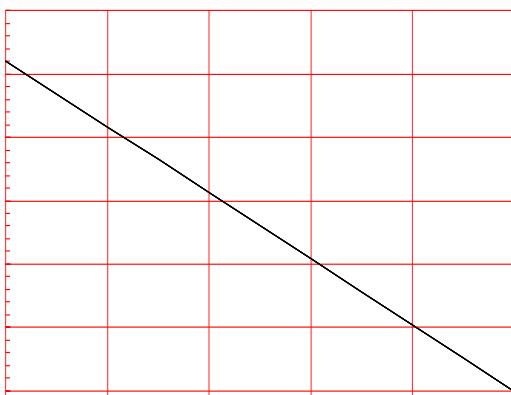
**FIG.1** Maximum power dissipation versus RMS on-state current



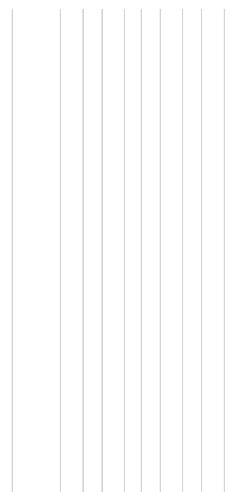
**FIG.2:** RMS on-state current versus case temperature



**FIG.3:** RMS on-state current versus ambient temperature (printed circuit board FR4,copper thickness:35 $\mu$ m)(full cycle)



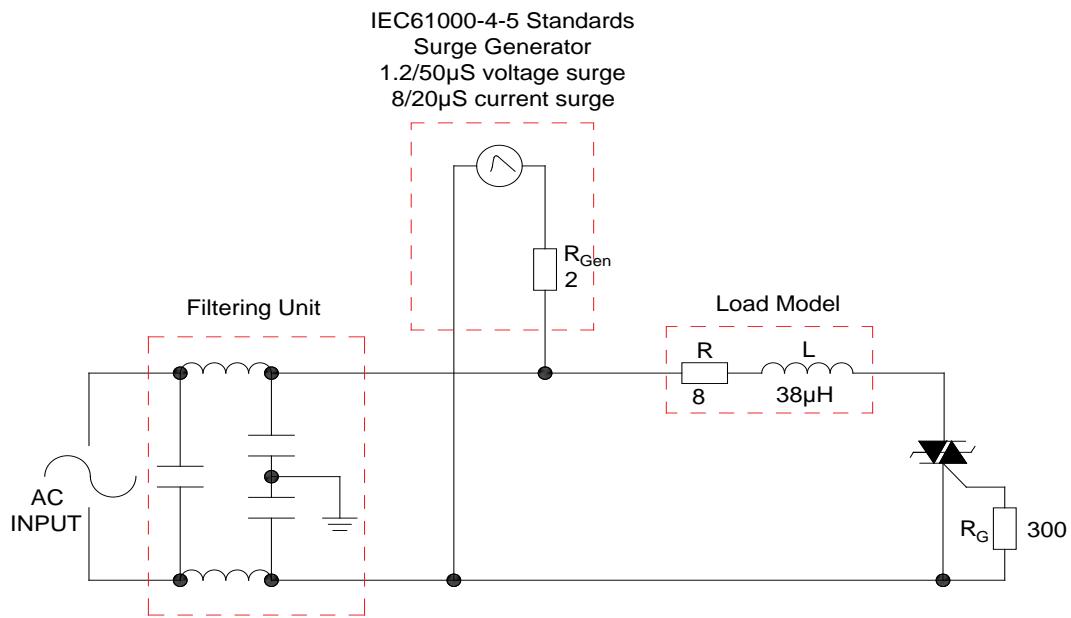
**FIG.4:** Surge peak on-state current versus number of cycles



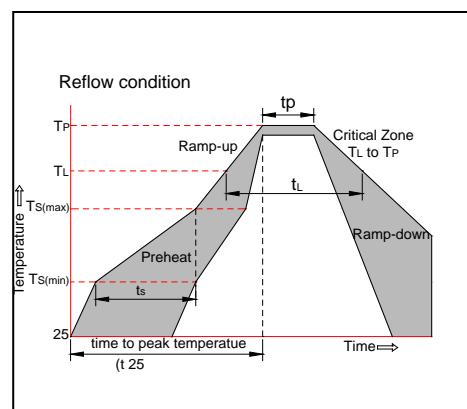
**ACJT610-8K**

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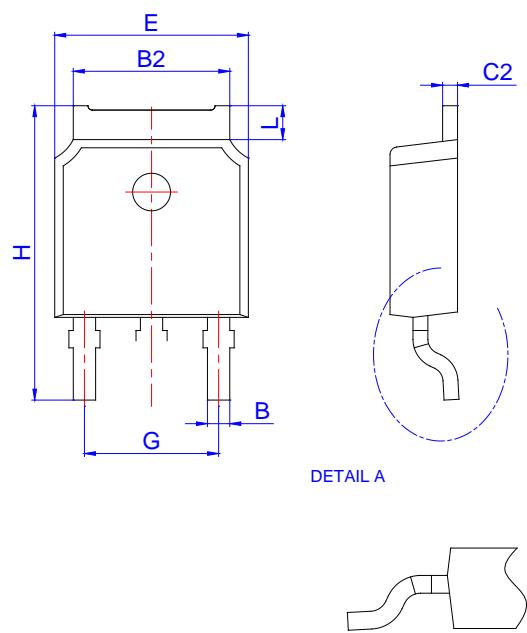
FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	+150
	-Temperature Max( $T_{s(max)}$ )	+200
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ )to peak)		3 /sec. Max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		3 /sec. Max
Reflow	-Temperature( $T_L$ )(Liquidus)	+217
	-Temperature( $t_L$ )	60-150 secs.
Peak Temp ( $T_p$ )		+260(+0/-5)
Time within 5% of actual Peak Temp ( $t_p$ )		20-40secs.
Ramp-down Rate		6 /sec. Max
Time 25% to Peak Temp ( $T_p$ )		8 min. Max
Do not exceed		+260







Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.15	0		0.006
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1						
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

